

# isc N-Channel MOSFET Transistor

## 20N06

### • FEATURES

- Drain Current  $I_D = 20A @ T_C = 25^\circ C$
- Drain Source Voltage-  
:  $V_{DSS} = 60V(\text{Min})$
- Static Drain-Source On-Resistance  
:  $R_{DS(on)} = 0.085 \Omega (\text{Max})$
- Fast Switching
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### • APPLICATIONS

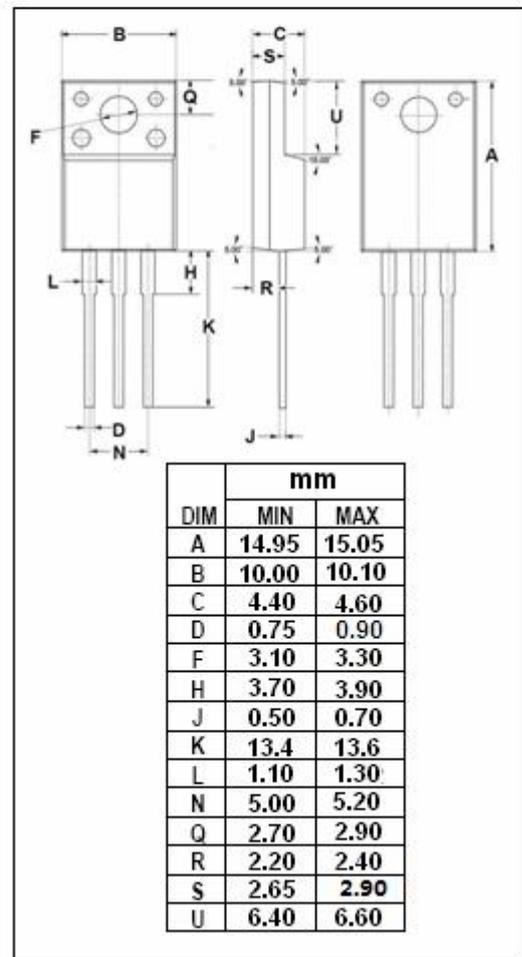
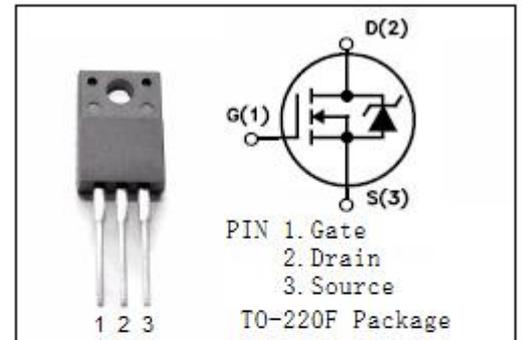
- Switching applications in power supplies
- Motor controls, high efficient DC to DC converters

### • ABSOLUTE MAXIMUM RATINGS( $T_a = 25^\circ C$ )

SYMBOL	PARAMETER	VALUE	UNIT
$V_{DSS}$	Drain-Source Voltage	60	V
$V_{GS}$	Gate-Source Voltage-Continuous	$\pm 30$	V
$I_D$	Drain Current-Continuous	20	A
$I_{DM}$	Drain Current-Single Plused	80	A
$P_D$	Total Dissipation @ $T_C = 25^\circ C$	40	W
$T_j$	Max. Operating Junction Temperature	150	$^\circ C$
$T_{stg}$	Storage Temperature	-55~150	$^\circ C$

### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th j-c}$	Thermal Resistance, Junction to Case	3.125	$^\circ C/W$



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## • ELECTRICAL CHARACTERISTICS

T<sub>c</sub>=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	MAX	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> =250μA	60			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> ; I <sub>D</sub> =250μA	2.0		4.0	V
V <sub>SD</sub>	Diode Forward On-voltage	I <sub>S</sub> = 20A; V <sub>GS</sub> = 0			1.7	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 10A			0.085	Ω
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> = ± 30V; V <sub>DS</sub> = 0			± 100	nA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =60V; V <sub>GS</sub> = 0			10	μA
C <sub>iss</sub>	Input Capacitance	V <sub>DS</sub> =25V;			850	pF
C <sub>rss</sub>	Reverse Transfer capacitance	V <sub>GS</sub> =0V;			150	
C <sub>oss</sub>	Output Capacitance	f <sub>r</sub> =1MHz			400	

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